

WN3S20S100CD

Dual power Schottky diode

Rev.01 - 14 November 2022

Product data sheet

1. General description

Dual common cathode power Schottky diode in TO252 (DPAK) plastic package.



2. Features and benefits

- Trench structure
- High junction temperature up to 150 °C
- · Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				100		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 114 °C; per diode; <u>Fig. 1; Fig. 2; Fig. 3</u>			10		A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; $T_{mb} \leq$ 113 °C; both diodes conducting		20			A
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_F = 10 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.90	1.00	V
I _R	reverse current	V _R = 100 V; T _j = 25 °C; per diode; <u>Fig. 7; Fig. 8</u>		-	2.5	15	μA

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	К	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode		5

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WN3S20S100CD	TO252	WN3S20S100CDJ	Reel	2500	TO252d	07-Sep-2022		

7. Marking

Table 4.	Marking	codes
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Type number	Marking codes
WN3S20S100CD	WN3S20S 100CD

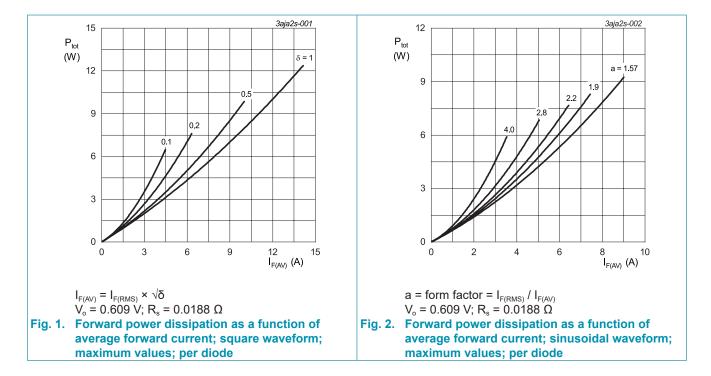
8. Limiting values

Table 5. Limiting values

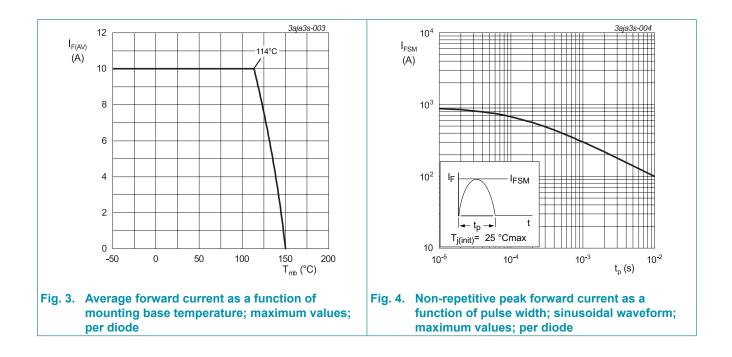
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			100	V
V_{RWM}	crest working reverse voltage			100	V
V _R	reverse voltage	DC		100	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 114 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		10	A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 113 °C; both diodes conducting		20	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>		100	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		110	A
T _{stg}	storage temperature			-40 to 150	°C
T _j	junction temperature		[1]	-40 to 150	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$

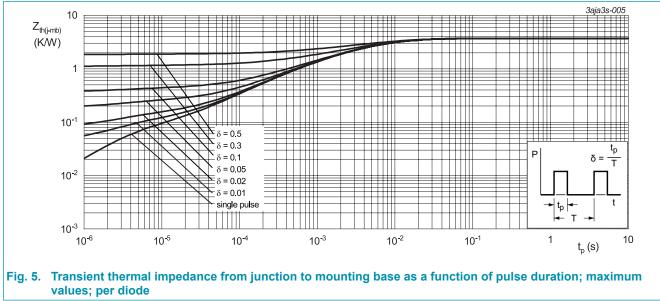


WN3S20S100CD Dual power Schottky diode



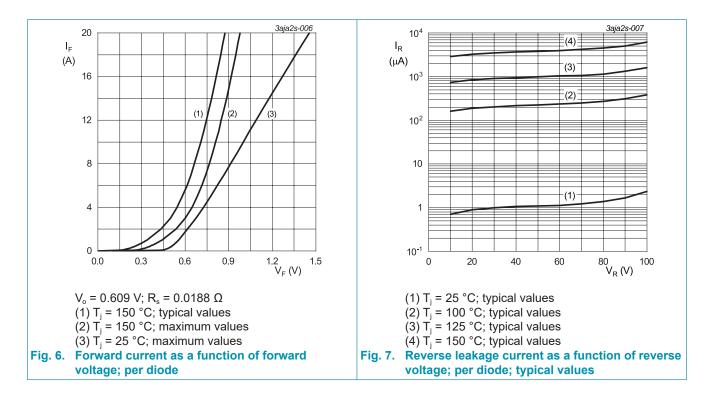
9. Thermal characteristics

Table 6. Thermal characteristics								
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
$R_{\text{th}(j\text{-}mb)}$	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>		-	-	3.7	K/W	
		both diodes conducting		-	-	1.9	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W	



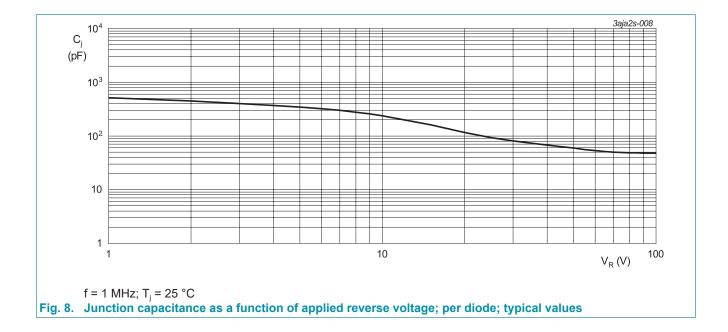
10. Characteristics

Fable 7. Cł	naracteristics							
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static characteristics								
V _F	forward voltage	$I_{F} = 10 \text{ A}; T_{j} = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.90	1.00	V	
		$I_F = 10 \text{ A}; T_j = 125 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.76	-	V	
I _R	reverse current	V _R = 100 V; T _j = 25 °C; per diode; Fig. 7; Fig. 8		-	2.5	15	μA	
		V _R = 100 V; T _j = 125 °C; per diode; <u>Fig. 7</u> ; <u>Fig. 8</u>		-	1.7	10	mA	

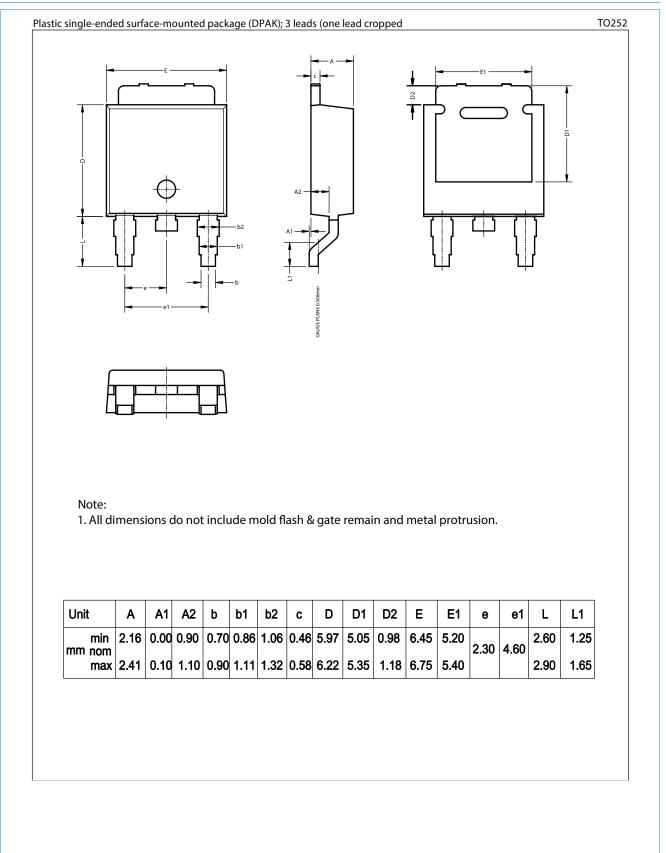


WN3S20S100CD

Dual power Schottky diode



11. Package outline



WN3S20S100CD

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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13. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	5
10. Characteristics	6
11. Package outline	8
12. Legal information	9
13. Contents	

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